



### 30V P-Channel Enhancement Mode MOSFET

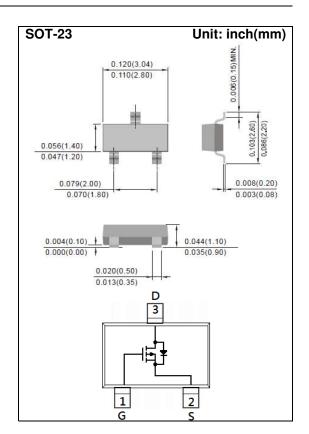
Voltage -30 V Current -2.9A

#### **Features**

- RDS(ON), VGS@-10V, ID@-2.9A<110m $\Omega$
- RDS(ON) , VGS@-4.5V, ID@-1.9A<150mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A09



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-30	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	-2.9	Α
Pulsed Drain Current		I <sub>DM</sub>	-11.6	Α
Power Dissipation	T <sub>a</sub> =25°C	$P_{D}$	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-1	-1.31	-2.1	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-2.9A	-	92	110	mΩ	
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-1.9A	-	120	150		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =-30V, $V_{GS}$ =0V	-	-0.01	-1	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	<u>+</u> 10	<u>+</u> 100	nA	
Dynamic							
Total Gate Charge	$Q_g$	V 45V L 0.0A	-	9.8	-	nC	
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ =-15V, $I_{D}$ =-2.9A, $V_{GS}$ =-10V (Note 1,2)	-	1.5	-		
Gate-Drain Charge	$Q_{gd}$		-	2.2	-		
Input Capacitance	Ciss	\\ 45\\\\\ 0\\	-	396	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	47	-		
Reverse Transfer Capacitance	Crss		-	36	-		
Switching							
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =-15V, $I_{D}$ =-2.9A, $V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	5	-		
Turn-On Rise Time	tr			30		ns	
Turn-Off Delay Time	td <sub>(off)</sub>		-	25	-		
Turn-Off Fall Time	tf	M <sub>G</sub> =012	-	8	-		
Drain-Source Diode							
Maximum Continuous Drain-Source		I <sub>S</sub>	-	-	-1.5	А	
Diode Forward Current	IS						
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V		-0.77	-1.2	V	

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### **TYPICAL CHARACTERISTIC CURVES**

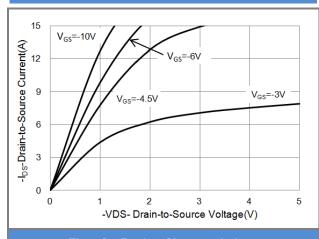


Fig.1 On-Region Characteristics

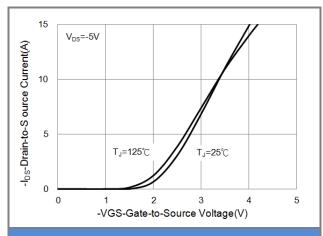


Fig.2 Transfer Characteristics

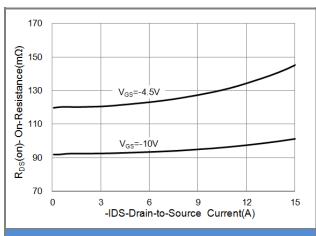


Fig.3 On-Resistance vs. Drain Current

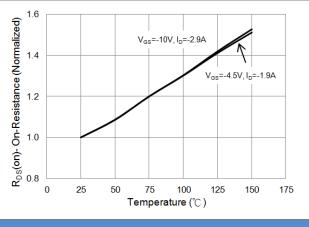
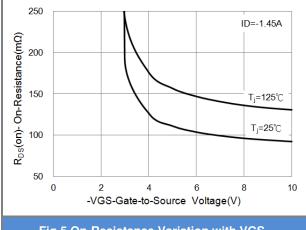
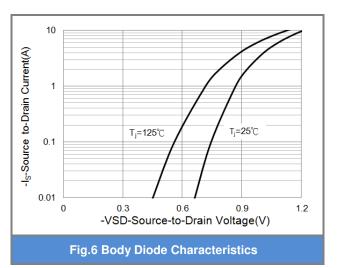


Fig.4 On-Resistance vs. Junction temperature











### **TYPICAL CHARACTERISTIC CURVES**

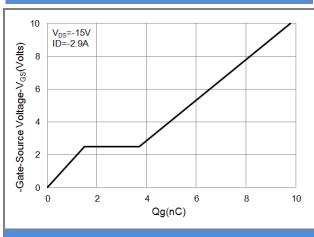


Fig.7 Gate-Charge Characteristics

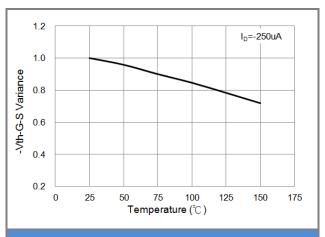


Fig.8 Threshold Voltage Variation with Temperature

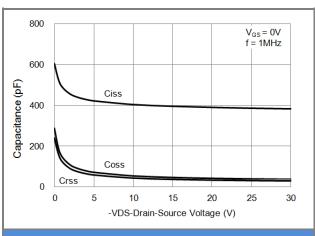


Fig.9 Capacitance vs. Drain-Source Voltage

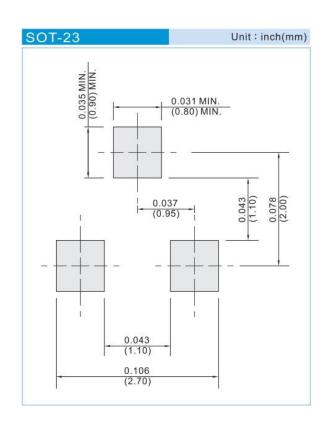




### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJA3409_R1_00001	SOT-23	3K pcs / 7" reel	A09	Halogen free
PJA3409_R2_00001	SOT-23	12K pcs / 13" reel	A09	Halogen free

## **MOUNTING PAD LAYOUT**







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